

CD4020BM/CD4020BC **14-Stage Ripple Carry Binary Counters** **CD4040BM/CD4040BC** **12-Stage Ripple Carry Binary Counters** **CD4060BM/CD4060BC** **14-Stage Ripple Carry Binary Counters**

General Description

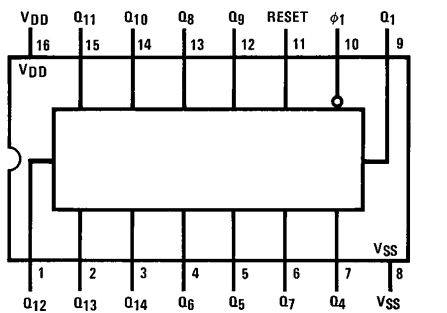
The CD4020BM/CD4020BC, CD4060BM/CD4060BC are 14-stage ripple carry binary counters, and the CD4040BM/CD4040BC is a 12-stage ripple carry binary counter. The counters are advanced one count on the negative transition of each clock pulse. The counters are reset to the zero state by a logical "1" at the reset input independent of clock.

Features

- Wide supply voltage range 1.0V to 15V
- High noise immunity 0.45 V_{DD} (typ.)
- Low power TTL compatibility Fan out of 2 driving 74L or 1 driving 74LS
- Medium speed operation 8 MHz typ. at $V_{DD} = 10V$
- Schmitt trigger clock input

Connection Diagrams

Dual-In-Line Package
CD4020BM/CD4020BC

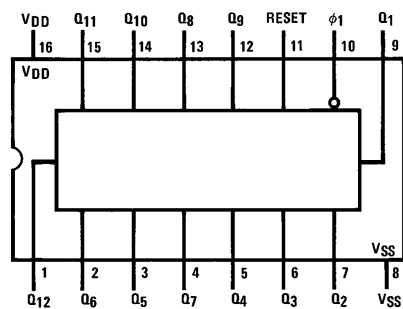


Top View

TL/F/5953-1

Order Number CD4020B, CD4040B or CD4060B

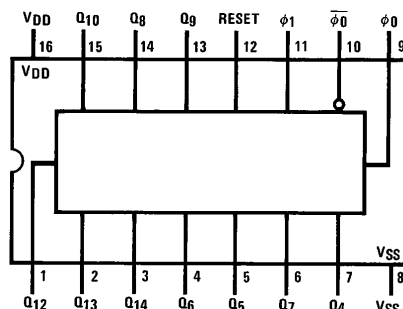
Dual-In-Line Package
CD4040BM/CD4040BC



Top View

TL/F/5953-2

Dual-In-Line Package
CD4060BM/CD4060BC



Top View

TL/F/5953-3

Absolute Maximum Ratings (Notes 1 and 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage (V_{DD})	−0.5V to +18V
Input Voltage (V_{IN})	−0.5V to V_{DD} + 0.5V
Storage Temperature Range (T_S)	−65°C to +150°C
Package Dissipation (P_D)	
Dual-In-Line	700 mW
Small Outline	500 mW
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions

Supply Voltage (V_{DD})	+3V to +15V
Input Voltage (V_{IN})	0V to V_{DD}
Operating Temperature Range (T_A)	
CD40XXBM	−55°C to +125°C
CD40XXBC	−40°C to +85°C

DC Electrical Characteristics CD40XXBM (Note 2)

Symbol	Parameter	Conditions	−55°C		+25°C			+125°C		Units
			Min	Max	Min	Typ	Max	Min	Max	
I_{DD}	Quiescent Device Current	$V_{DD} = 5V, V_{IN} = V_{DD}$ or V_{SS}		5			5		150	μA
		$V_{DD} = 10V, V_{IN} = V_{DD}$ or V_{SS}		10			10		300	μA
		$V_{DD} = 15V, V_{IN} = V_{DD}$ or V_{SS}		20			20		600	μA
V_{OL}	Low Level Output Voltage	$V_{DD} = 5V$		0.05		0	0.05		0.05	V
		$V_{DD} = 10V$		0.05		0	0.05		0.05	V
		$V_{DD} = 15V$		0.05		0	0.05		0.05	V
V_{OH}	High Level Output Voltage	$V_{DD} = 5V$	4.95		4.95	5		4.95		V
		$V_{DD} = 10V$	9.95		9.95	10		9.95		V
		$V_{DD} = 15V$	14.95		14.95	15		14.95		V
V_{IL}	Low Level Input Voltage	$V_{DD} = 5V, V_O = 0.5V$ or 4.5V		1.5		2	1.5		1.5	V
		$V_{DD} = 10V, V_O = 1.0V$ or 9.0V		3.0		4	3.0		3.0	V
		$V_{DD} = 15V, V_O = 1.5V$ or 13.5V		4.0		6	4.0		4.0	V
V_{IH}	High Level Input Voltage	$V_{DD} = 5V, V_O = 0.5V$ or 4.5V	3.5		3.5	3		3.5		V
		$V_{DD} = 10V, V_O = 1.0V$ or 9.0V	7.0		7.0	6		7.0		V
		$V_{DD} = 15V, V_O = 1.5V$ or 13.5V	11.0		11.0	9		11.0		V
I_{OL}	Low Level Output Current (See Note 3)	$V_{DD} = 5V, V_O = 0.4V$	0.64		0.51	0.88		0.36		mA
		$V_{DD} = 10V, V_O = 0.5V$	1.6		1.3	2.25		0.9		mA
		$V_{DD} = 15V, V_O = 1.5V$	4.2		3.4	8.8		2.4		mA
I_{OH}	High Level Output Current (See Note 3)	$V_{DD} = 5V, V_O = 4.6V$	−0.64		−0.51	−0.88		−0.36		mA
		$V_{DD} = 10V, V_O = 9.5V$	−1.6		−1.3	−2.25		−0.9		mA
		$V_{DD} = 15V, V_O = 13.5V$	−4.2		−3.4	−8.8		−2.4		mA
I_{IN}	Input Current	$V_{DD} = 15V, V_{IN} = 0V$		−0.10		10^{-5}	−0.10		−1.0	μA
		$V_{DD} = 15V, V_{IN} = 15V$		0.10		10^{-5}	0.10		1.0	μA

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and "Electrical Characteristics" provide conditions for actual device operation.

Note 2: $V_{SS} = 0V$ unless otherwise specified.

Note 3: Data does not apply to oscillator points ϕ_0 and $\overline{\phi_0}$ of CD4060BM/CD4060BC. I_{OH} and I_{OL} are tested one output at a time.

DC Electrical Characteristics 40XXBC (Note 2)

Symbol	Parameter	Conditions	−40°C		+25°C			+85°C		Units
			Min	Max	Min	Typ	Max	Min	Max	
I_{DD}	Quiescent Device Current	$V_{DD} = 5V, V_{IN} = V_{DD}$ or V_{SS}		20			20		150	μA
		$V_{DD} = 10V, V_{IN} = V_{DD}$ or V_{SS}		40			40		300	μA
		$V_{DD} = 15V, V_{IN} = V_{DD}$ or V_{SS}		80			80		600	μA
V_{OL}	Low Level Output Voltage	$V_{DD} = 5V$		0.05		0	0.05		0.05	V
		$V_{DD} = 10V$		0.05		0	0.05		0.05	V
		$V_{DD} = 15V$		0.05		0	0.05		0.05	V

DC Electrical Characteristics 40XXBC (Note 2) (Continued)

Symbol	Parameter	Conditions	−40°C		+25°C			+85°C		Units
			Min	Max	Min	Typ	Max	Min	Max	
V _{OH}	High Level Output Voltage	V _{DD} = 5V	4.95		4.95	5		4.95		V
		V _{DD} = 10V	9.95		9.95	10		9.95		V
		V _{DD} = 15V	14.95		14.95	15		14.95		V
V _{IL}	Low Level Input Voltage	V _{DD} = 5V, V _O = 0.5V or 4.5V		1.5		2	1.5		1.5	V
		V _{DD} = 10V, V _O = 1.0V or 9.0V		3.0		4	3.0		3.0	V
		V _{DD} = 15V, V _O = 1.5V or 13.5V		4.0		6	4.0		4.0	V
V _{IH}	High Level Input Voltage	V _{DD} = 5V, V _O = 0.5V or 4.5V	3.5		3.5	3		3.5		V
		V _{DD} = 10V, V _O = 1.0V or 9.0V	7.0		7.0	6		7.0		V
		V _{DD} = 15V, V _O = 1.5V or 13.5V	11.0		11.0	9		11.0		V
I _{OL}	Low Level Output Current (See Note 3)	V _{DD} = 5V, V _O = 0.4V	0.52		0.44	0.88		0.36		mA
		V _{DD} = 10V, V _O = 0.5V	1.3		1.1	2.25		0.9		mA
		V _{DD} = 15V, V _O = 1.5V	3.6		3.0	8.8		2.4		mA
I _{OH}	High Level Output Current (See Note 3)	V _{DD} = 5V, V _O = 4.6V	−0.52		−0.44	−0.88		−0.36		mA
		V _{DD} = 10V, V _O = 9.5V	−1.3		−1.1	−2.25		−0.9		mA
		V _{DD} = 15V, V _O = 13.5V	−3.6		−3.0	−8.8		−2.4		mA
I _{IN}	Input Current	V _{DD} = 15V, V _{IN} = 0V		−0.30		−10 ^{−5}	−0.30		−1.0	μA
		V _{DD} = 15V, V _{IN} = 15V		0.30		10 ^{−5}	0.30		1.0	μA

AC Electrical Characteristics* CD4020BM/CD4020BC, CD4040BM/CD4040BC

T_A = 25°C, C_L = 50 pF, R_L = 200k, t_r = t_f = 20 ns, unless otherwise noted

Symbol	Parameter	Conditions	Min	Typ	Max	Units
t _{PHL1} , t _{PLH1}	Propagation Delay Time to Q ₁	V _{DD} = 5V		250	550	ns
		V _{DD} = 10V		100	210	ns
		V _{DD} = 15V		75	150	ns
t _{PHL} , t _{PLH}	Interstage Propagation Delay Time from Q _n to Q _{n+1}	V _{DD} = 5V		150	330	ns
		V _{DD} = 10V		60	125	ns
		V _{DD} = 15V		45	90	ns
t _{THL} , t _{TLH}	Transition Time	V _{DD} = 5V		100	200	ns
		V _{DD} = 10V		50	100	ns
		V _{DD} = 15V		40	80	ns
t _{WL} , t _{WH}	Minimum Clock Pulse Width	V _{DD} = 5V		125	335	ns
		V _{DD} = 10V		50	125	ns
		V _{DD} = 15V		40	100	ns
t _{rCL} , t _{fCL}	Maximum Clock Rise and Fall Time	V _{DD} = 5V			No Limit	ns
		V _{DD} = 10V			No Limit	ns
		V _{DD} = 15V			No Limit	ns
f _{CL}	Maximum Clock Frequency	V _{DD} = 5V	1.5	4		MHz
		V _{DD} = 10V	4	10		MHz
		V _{DD} = 15V	5	12		MHz
t _{PHL(R)}	Reset Propagation Delay	V _{DD} = 5V		200	450	ns
		V _{DD} = 10V		100	210	ns
		V _{DD} = 15V		80	170	ns
t _{WH(R)}	Minimum Reset Pulse Width	V _{DD} = 5V		200	450	ns
		V _{DD} = 10V		100	210	ns
		V _{DD} = 15V		80	170	ns
C _{in}	Average Input Capacitance	Any Input		5	7.5	pF
C _{pd}	Power Dissipation Capacitance			50		pF

*AC Parameters are guaranteed by DC correlated testing.

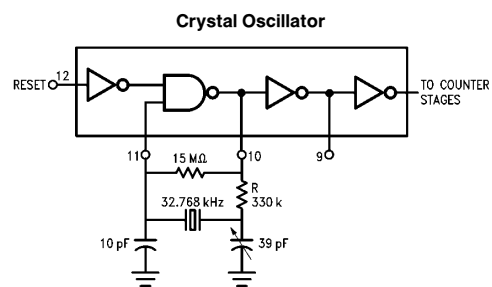
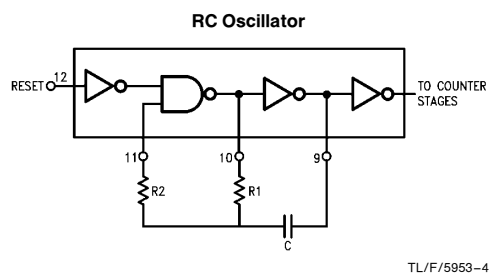
AC Electrical Characteristics* CD4060BM/CD4060BC

$T_A = 25^\circ\text{C}$, $C_L = 50\text{ pF}$, $R_L = 200\text{ k}$, $t_r = t_f = 20\text{ ns}$, unless otherwise noted

Symbol	Parameter	Conditions	Min	Typ	Max	Units
t_{PHL4} , t_{PLH4}	Propagation Delay Time to Q_4	$V_{DD} = 5\text{V}$ $V_{DD} = 10\text{V}$ $V_{DD} = 15\text{V}$		550 250 200	1300 525 400	ns ns ns
t_{PHL} , t_{PLH}	Interstage Propagation Delay Time from Q_n to Q_{n+1}	$V_{DD} = 5\text{V}$ $V_{DD} = 10\text{V}$ $V_{DD} = 15\text{V}$		150 60 45	330 125 90	ns ns ns
t_{THL} , t_{TLH}	Transition Time	$V_{DD} = 5\text{V}$ $V_{DD} = 10\text{V}$ $V_{DD} = 15\text{V}$		100 50 40	200 100 80	ns ns ns
t_{WL} , t_{WH}	Minimum Clock Pulse Width	$V_{DD} = 5\text{V}$ $V_{DD} = 10\text{V}$ $V_{DD} = 15\text{V}$		170 65 50	500 170 125	ns ns ns
t_{rCL} , t_{fCL}	Maximum Clock Rise and Fall Time	$V_{DD} = 5\text{V}$ $V_{DD} = 10\text{V}$ $V_{DD} = 15\text{V}$			No Limit No Limit No Limit	ns ns ns
f_{CL}	Maximum Clock Frequency	$V_{DD} = 5\text{V}$ $V_{DD} = 10\text{V}$ $V_{DD} = 15\text{V}$	1 3 4	3 8 10		MHz MHz MHz
$t_{PHL(R)}$	Reset Propagation Delay	$V_{DD} = 5\text{V}$ $V_{DD} = 10\text{V}$ $V_{DD} = 15\text{V}$		200 100 80	450 210 170	ns ns ns
$t_{WH(R)}$	Minimum Reset Pulse Width	$V_{DD} = 5\text{V}$ $V_{DD} = 10\text{V}$ $V_{DD} = 15\text{V}$		200 100 80	450 210 170	ns ns ns
C_{in}	Average Input Capacitance	Any Input		5	7.5	pF
C_{pd}	Power Dissipation Capacitance			50		pF

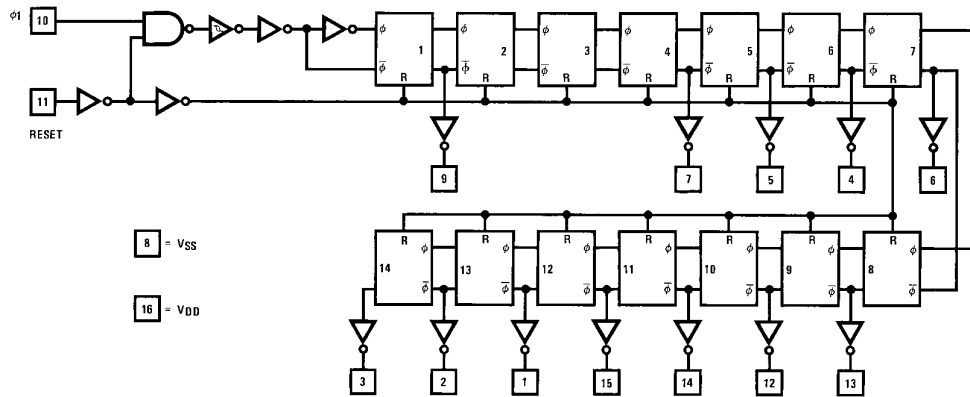
*AC Parameters are guaranteed by DC correlated testing.

CD4060B Typical Oscillator Connections



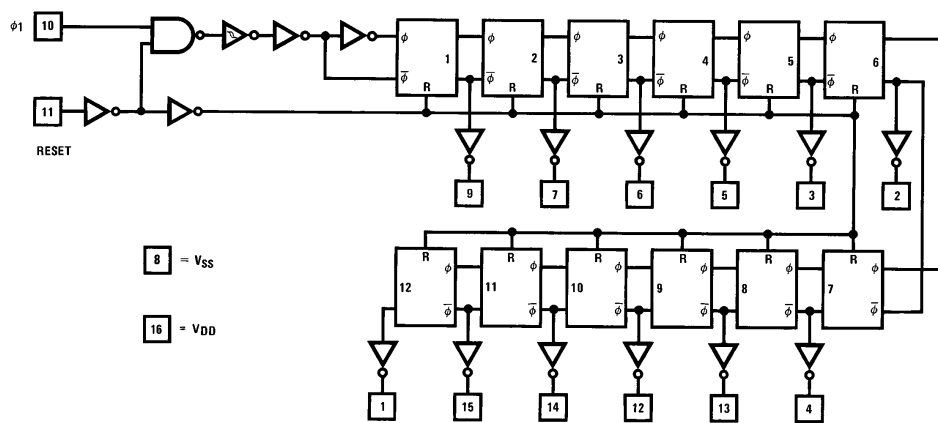
Schematic Diagrams

CD4020BM/CD4020BC Schematic Diagram



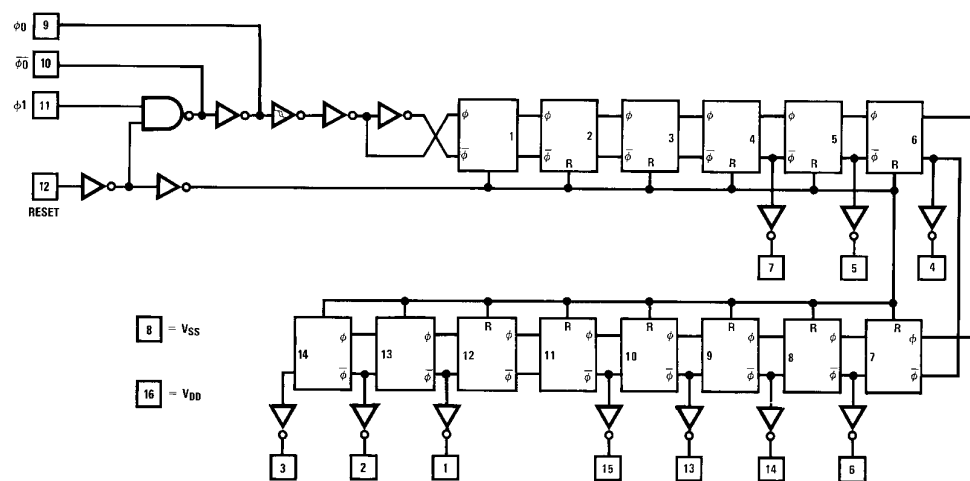
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CD4040BM/CD4040BC Schematic Diagram



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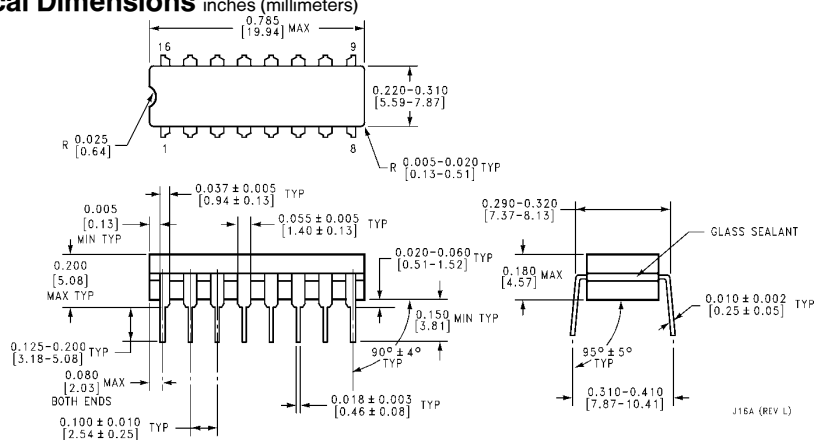
CD4060BM/CD4060BC Schematic Diagram



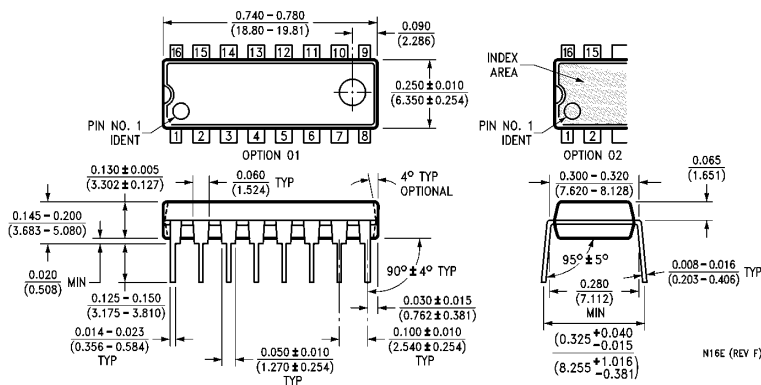
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CD4020BM/BC 14-Stage Ripple Carry Binary Counters/CD4040BM/BC 12-Stage Ripple Carry Binary Counters CD4060BM/BC 14-Stage Ripple Carry Binary Counters

Physical Dimensions inches (millimeters)



Ceramic Dual-In-Line Package (J)
Order Number CD4020BMJ, CD4020BCJ,
CD4040BMJ, CD4040BCJ, CD4060BMJ or CD4060BCJ
NS Package Number J16A



Molded Dual-In-Line Package (N)
Order Number CD4020BMN, CD4020BCN,
CD4040BMN, CD4040BCN, CD4060BMN or CD4060BCN
NS Package Number N16E

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